



**DMN2710UWQ** 

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
201/	0.45Ω @ V <sub>GS</sub> = 4.5V	0.9A
20V	0.6Ω @ V <sub>GS</sub> = 2.5V	0.8A

## **Description and Applications**

This MOSFET has been designed to minimize the on-state resistance (RDs(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- General Purpose Interfacing Switch
- Power Management Functions
- DC-DC Converters
- Analog Switch

#### 20V N-CHANNEL ENHANCEMENT MODE MOSFET

## **Features and Benefits**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN2710UWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.027 grams (Approximate)

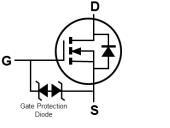


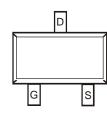
Notes:



SOT323

Top View





Equivalent Circuit

Top View

#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2710UWQ-7	SOT323	3,000/Tape & Reel
DMN2710UWQ-13	SOT323	10,000/Tape & Reel

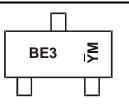
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



 $\label{eq:matrix} \begin{array}{l} \underline{B}E3 = Product Type Marking Code\\ \overline{Y}M = Date Code Marking\\ \overline{Y} = Year (ex: H = 2020)\\ M = Month (ex: 9 = September) \end{array}$ 

Date Code Key

	2020	2021	2022	2023	2024	2025	2026	2027	2020	2029	2020	2024
Year	2020	2021	2022	2023	2024	2025	2020	2027	2028	2029	2030	2031
Code	н	1	J	ĸ	L	М	N	0	Р	R	S	Т
					-			•				-
			-					-				-
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



## Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			VDSS	20	V
Gate-Source Voltage			V <sub>GSS</sub>	±6	V
Continuous Drain Current (Note 6) $V_{GS}$ = 4.5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	0.9 0.7	А
Pulsed Drain Current (10µs Pulse, Duty Cycle=1%)			ldм	5	A
Maximum Body Diode Forward Current (Note 5)			ls	0.6	A

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.47	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	268	°C/W
Total Power Dissipation (Note 6)		PD	0.6	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>θJA</sub>	212	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

#### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

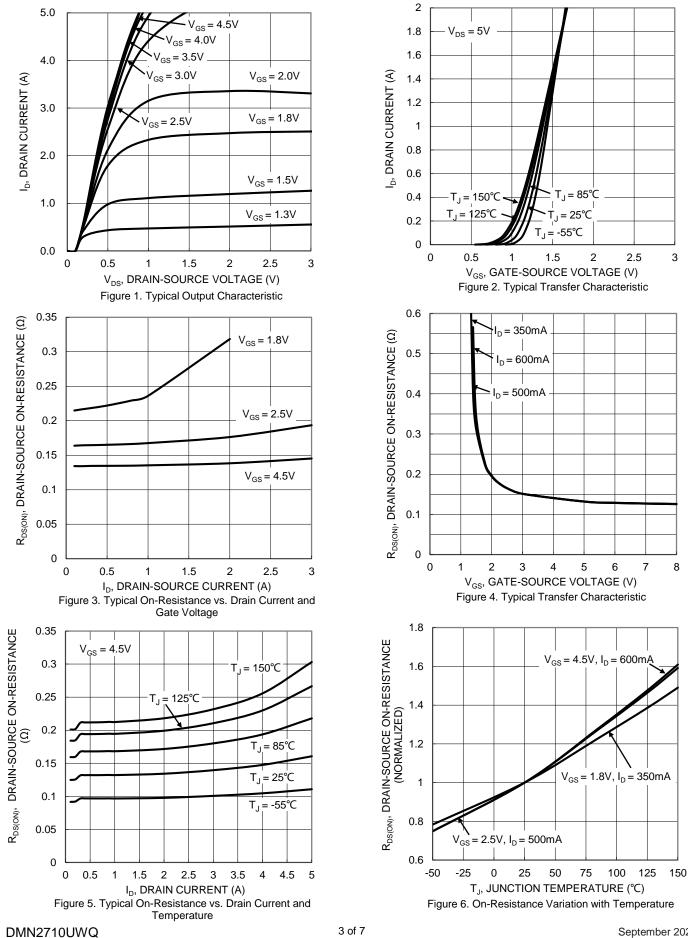
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	<b>,</b>		- 71-			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	20	—		V	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250µA
Zero Gate Voltage Drain Current @T <sub>C</sub> = +25°	C IDSS	_	—	100	nA	V <sub>DS</sub> =20V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>	_	—	±1.0	μA	$V_{GS} = \pm 4.5 V, V_{DS} = 0 V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	0.5	—	1.0	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
			0.13	0.45		VGS = 4.5V, ID = 600mA
Static Drain-Source On-Resistance	RDS(ON)		0.16	0.6	Ω	VGS = 2.5V, ID = 500mA
			0.22	0.75		$V_{GS} = 1.8V, I_D = 350mA$
Diode Forward Voltage	Vsd		0.7	1.2	V	VGS = 0V, IS = 150mA
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		42	—	pF	
Output Capacitance	Coss		13		pF	$V_{DS} = 16V, V_{GS} = 0V$ f = 1.0MHz
Reverse Transfer Capacitance	Crss		6.5	_	pF	1 = 1.0MH2
Total Gate Charge	Qg		0.6		nC	
Gate-Source Charge	Qgs	_	0.1	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$
Gate-Drain Charge	Qgd	_	0.1		nC	I <sub>D</sub> = 250mA
Turn-On Delay Time	td(on)	_	4.9	_	ns	
Turn-On Rise Time	t <sub>R</sub>		3.1		ns	$V_{DD} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time	tD(OFF)		386		ns	$R_L = 47\Omega, R_g = 10\Omega$
Turn-Off Fall Time	t⊨	—	174	—	ns	I <sub>D</sub> = 200mA
Reverse Recovery Time	t <sub>RR</sub>	—	88		ns	I <sub>F</sub> = 1.0A, di/dt = 100A/µs
Reverse Recovery Charge	QRR	_	29	_	nC	IF = 1.0A, di/dt = 100A/µs

Notes:

Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



# DMN2710UWQ

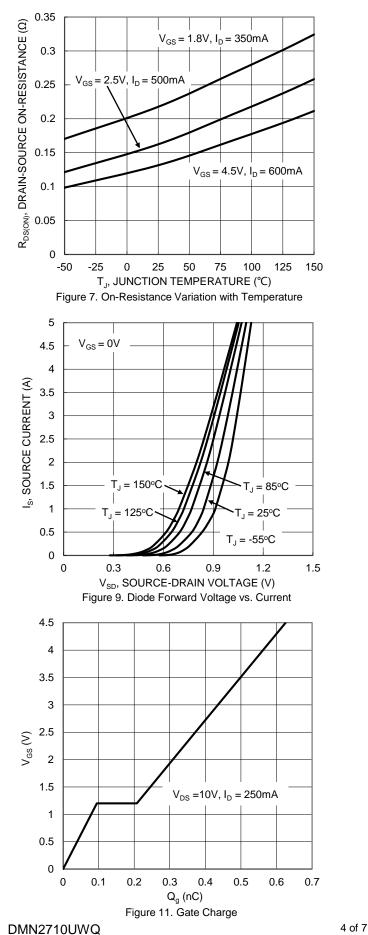


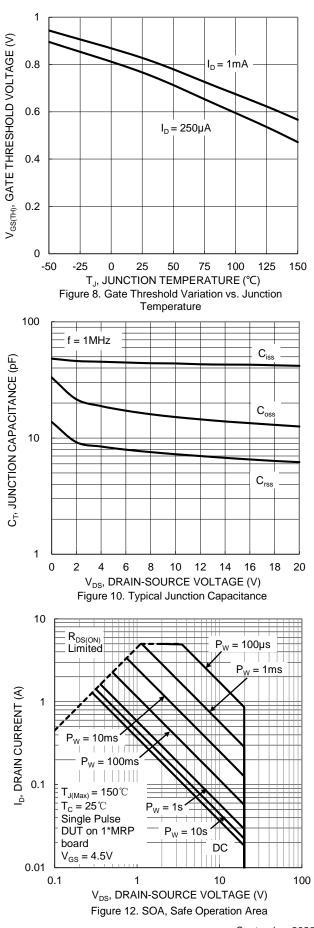
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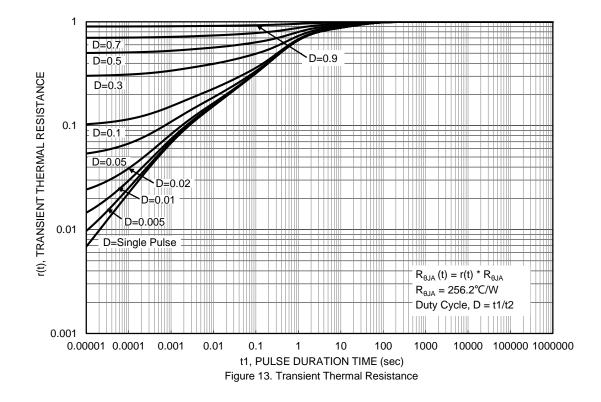


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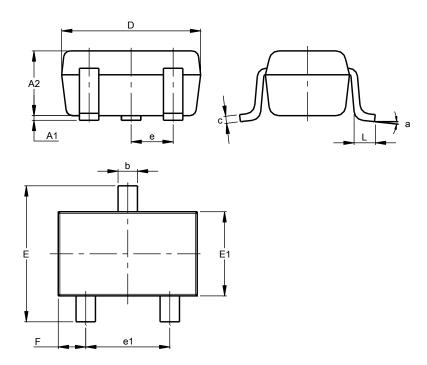




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

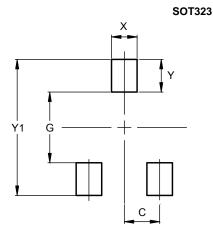




SOT323						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.90	1.00	0.95			
b	0.25	0.40	0.30			
c	0.10	0.18	0.11			
D	1.80	2.20	2.15			
ш	2.00	2.20	2.10			
E1	1.15	1.35	1.30			
e	C	).650 B	SC			
e1	1.20	1.40	1.30			
F	0.375	0.475	0.425			
L	0.25	0.40	0.30			
а	0°	8°				
All	Dimen	sions i	in mm			

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500

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